

2SD968, 2SD968A

Silicon NPN epitaxial planer type

For low-frequency driver amplification

Complementary to 2SB789 and 2SB789A

Features

- High collector to emitter voltage V_{CEO} .
- Large collector power dissipation P_C .
- Mini Power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

Parameter		Symbol	Ratings	Unit
Collector to base voltage	2SD968	V_{CBO}	100	V
	2SD968A		120	
Collector to emitter voltage	2SD968	V_{CEO}	100	V
	2SD968A		120	
Emitter to base voltage		V_{EBO}	5	V
Peak collector current		I_{CP}	1	A
Collector current		I_C	0.5	A
Collector power dissipation		P_C^*	1	W
Junction temperature		T_j	150	°C
Storage temperature		T_{stg}	-55 ~ +150	°C

* Printed circuit board: Copper foil area of 1cm^2 or more, and the board thickness of 1.7mm for the collector portion

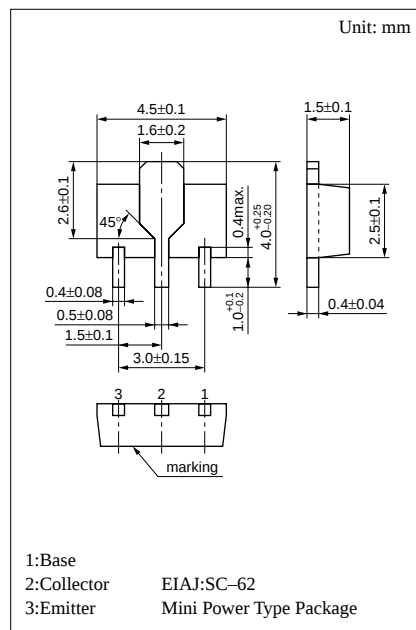
Electrical Characteristics ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector to emitter voltage	2SD968 2SD968A	V_{CEO}	$I_C = 100\mu\text{A}, I_B = 0$	100		V
				120		
Emitter to base voltage	V_{EBO}	$I_E = 10\mu\text{A}, I_C = 0$	5			V
Forward current transfer ratio	h_{FE1}^{*1}	$V_{CE} = 10\text{V}, I_C = 150\text{mA}^{*2}$	90		220	
	h_{FE2}	$V_{CE} = 5\text{V}, I_C = 500\text{mA}^{*2}$	50	100		
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}^{*2}$		0.2	0.6	V
Base to emitter saturation voltage	$V_{BE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}^{*2}$		0.85	1.2	V
Transition frequency	f_T	$V_{CB} = 10\text{V}, I_E = -50\text{mA}, f = 200\text{MHz}$		120		MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10\text{V}, I_E = 0, f = 1\text{MHz}$		11	20	pF

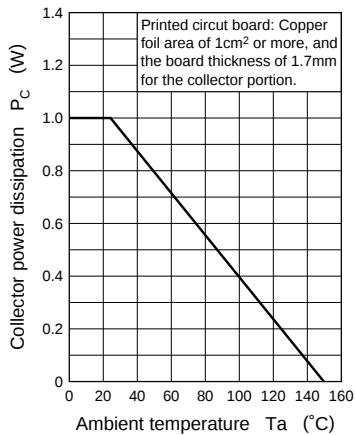
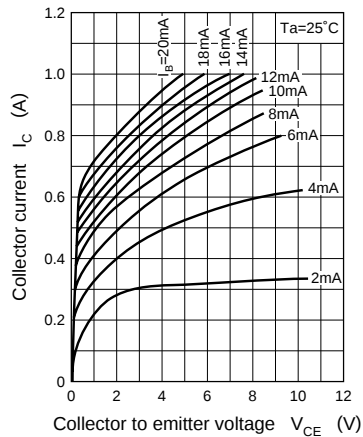
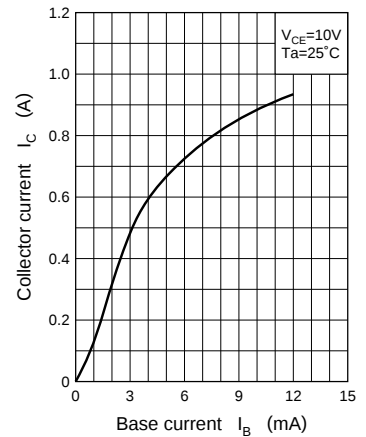
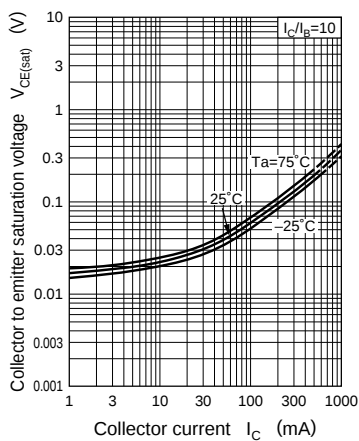
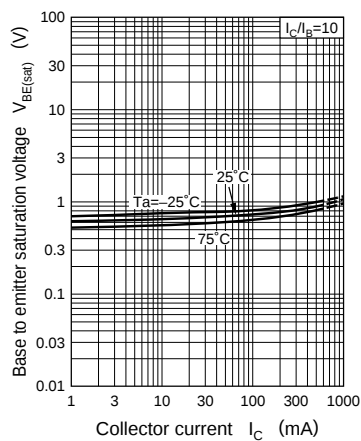
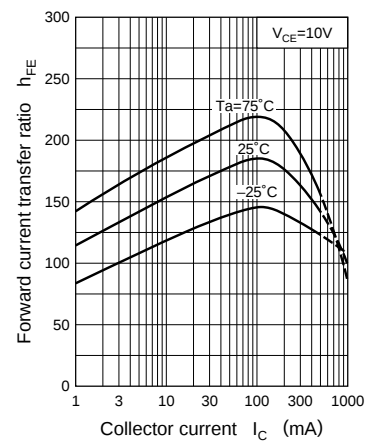
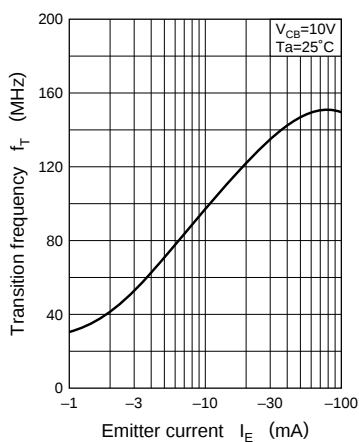
^{*1} h_{FE1} Rank classification

^{*2} Pulse measurement

Rank	Q	R
h_{FE1}	90 ~ 155	130 ~ 220
Marking	2SD968	WQ
Symbol	2SD968A	VR



Marking symbol : W(2SD968)
V(2SD968A)

$P_C - T_a$  $I_C - V_{CE}$  $I_C - I_B$  $V_{CE(sat)} - I_C$  $V_{BE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_E$  $C_{ob} - V_{CB}$ 